



DUAL SURFACE MOUNT NPN TRANSISTORS

This device contains two electrically-isolated 2N2222A NPN transistors. The two transistors have well matched hFE and are encapsulated in an ultra-small SOT-363 package. This device is ideal for portable applications where board space is at a premium.

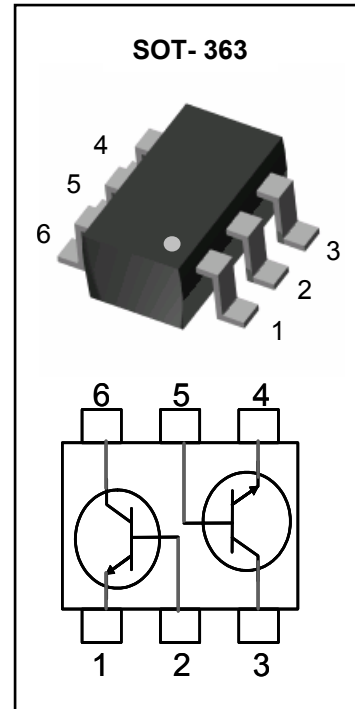
FEATURES

- Electrically Isolated Dual NPN Switching Transistor
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. . (Halogen Free)

APPLICATIONS

- General Purpose Amplifier Applications
- Hand-Held Computers, PDAs

Device Marking Code: M2A



MAXIMUM RATINGS

$T_J = 25^{\circ}\text{C}$ Unless otherwise noted

Rating	Symbol	Value	Units
Collector-Base Voltage	V_{CBO}	75	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current	I_C	600	mA
Total Power Dissipation (Note 1)	P_D	225A	mW
Operating Junction Temperature Range	T_J	-55 to +150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Units
Thermal Resistance, Junction to Ambient (Note 1)	R_{thja}	625	$^{\circ}\text{C}/\text{W}$

Note 1. FR-4 board 60 x 70 x 1mm with minimum recommended pad layout



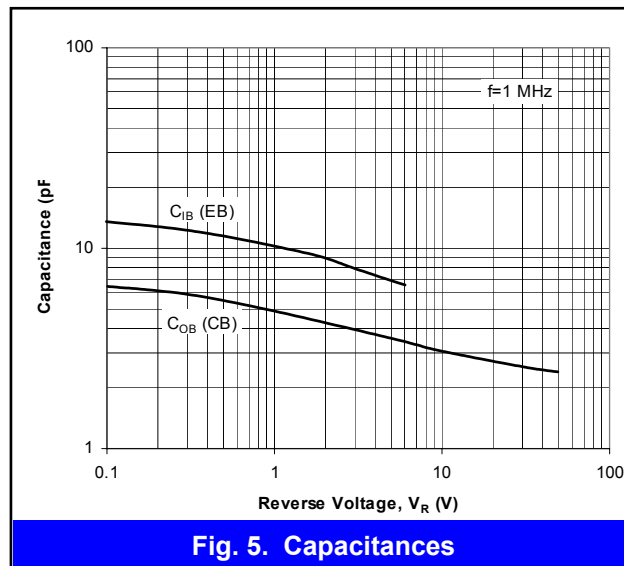
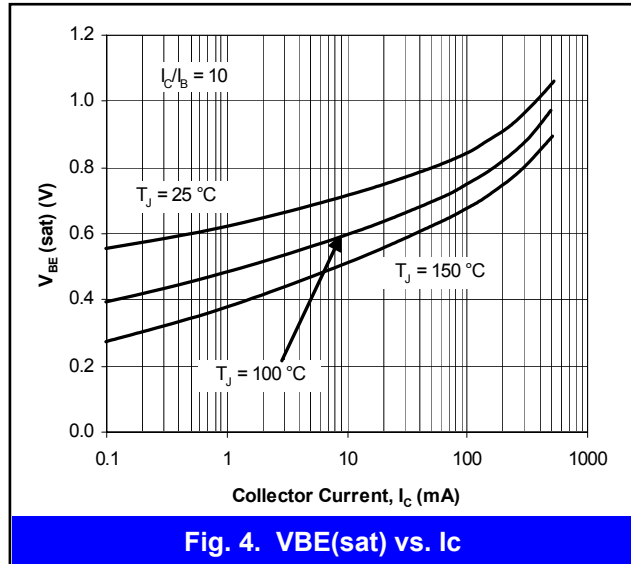
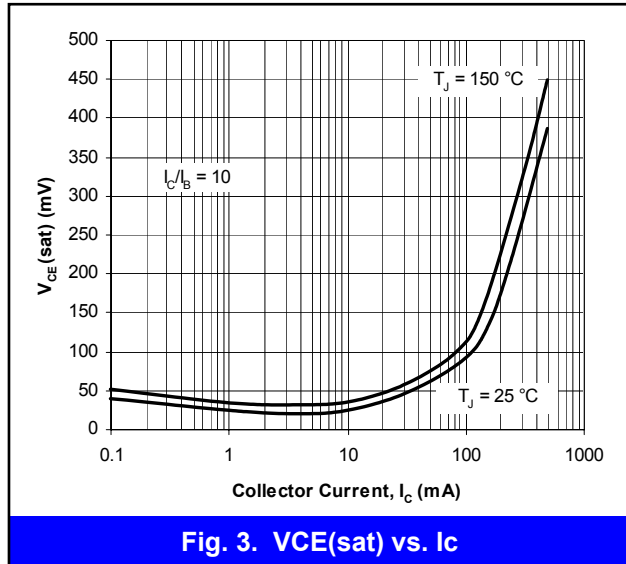
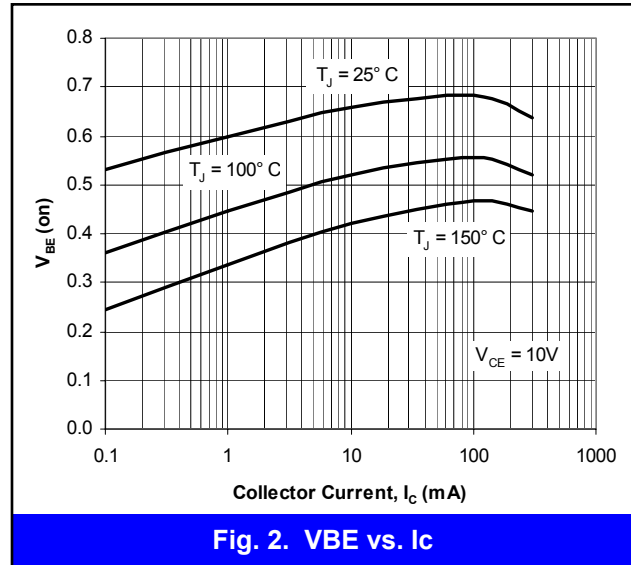
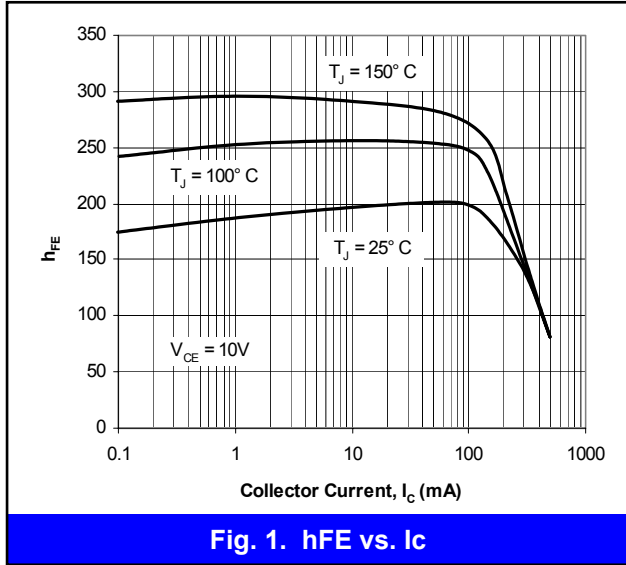
ELECTRICAL CHARACTERISTICS (Each Transistor) $T_J = 25^\circ\text{C}$ Unless otherwise noted

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}$	40	-	-	V
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\mu\text{A}$	75	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}$	6.0	-	-	V
Collector Cutoff Current	I_{CEX}	$V_{CE} = 60\text{V}, V_{EB} = 3.0\text{V}$	-	-	10	nA
Base Cutoff Current	I_{BL}	$V_{CE} = 60\text{V}, V_{EB} = 3.0\text{V}$	-	-	20	nA
DC Current Gain (Note 2)	h_{FE}	$I_C = 0.1\text{mA}, V_{CE} = 10\text{V}$	35	-	-	
		$I_C = 1.0\text{mA}, V_{CE} = 10\text{V}$	50	-	-	
		$I_C = 10\text{mA}, V_{CE} = 10\text{V}$	75	-	-	
		$I_C = 10\text{mA}, V_{CE} = 10\text{V}, T_J = -55^\circ\text{C}$	50	-	-	-
		$I_C = 150\text{mA}, V_{CE} = 10\text{V}$	100	-	300	
		$I_C = 500\text{mA}, V_{CE} = 10\text{V}$	40	-	-	
Collector-Emitter Saturation Voltage (Note 2)	$V_{CE(SAT)}$	$I_C = 150\text{mA}, I_B = 15\text{mA}$	-	-	0.3	V
		$I_C = 500\text{mA}, I_B = 50\text{mA}$	-	-	1.0	V
Base-Emitter Saturation Voltage (Note 2)	$V_{BE(SAT)}$	$I_C = 150\text{mA}, I_B = 15\text{mA}$	0.6	-	1.2	V
		$I_C = 500\text{mA}, I_B = 50\text{mA}$	-	-	2.0	
Gain-Bandwidth Product	f_T	$V_{CE} = 20\text{V}, I_C = 20\text{mA}$ $f = 100\text{MHz}$	300	-	-	MHz
Collector-Base Capacitance	C_{CBO}	$V_{CB} = 10\text{V}, f = 1.0\text{MHz}$	-	-	8.0	pF
Emitter-Base Capacitance	C_{EBO}	$V_{EB} = 0.5\text{V}, f = 1.0\text{MHz}$	-	-	25	pF
Delay Time	t_d	$V_{CC} = 30\text{V}, I_C = 150\text{mA}$	-	-	10	ns
Rise Time	t_r	$V_{BE(off)} = -0.5\text{V}, I_{B1} = 15\text{mA}$	-	-	25	ns
Storage Time	t_s	$V_{CC} = 30\text{V}, I_C = 150\text{mA}$	-	-	225	ns
Fall Time	t_f	$I_{B1} = I_{B2} = 15\text{mA}$	-	-	60	ns

Note 2. Short duration test pulse used to minimize self-heating

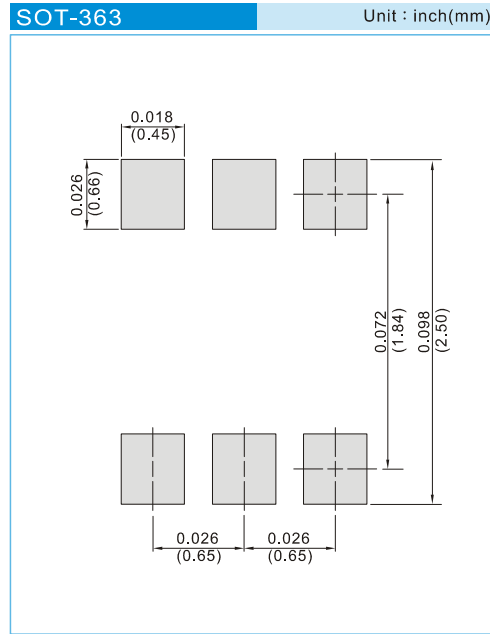
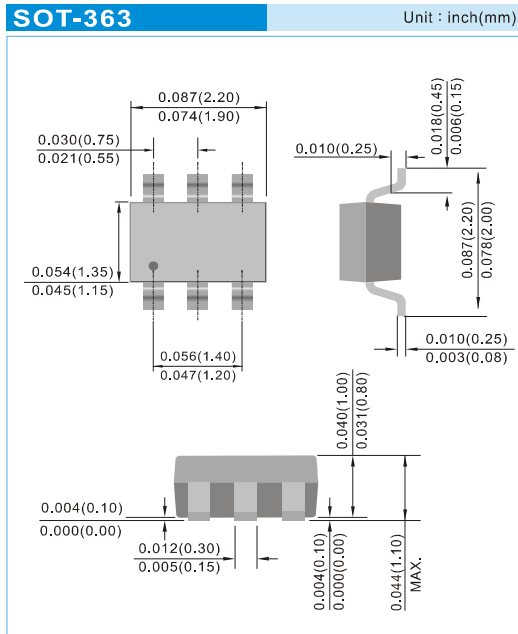


CHARACTERISTICS CURVES (Each Transistor) $T_J = 25^\circ\text{C}$ Unless otherwise noted





PACKAGE LAYOUT AND SUGGESTED PAD DIMENSIONS





MMDT2222A

Part No_packing code_Version

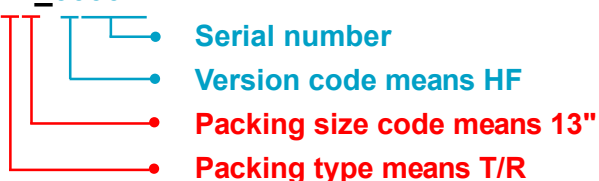
MMDT2222A_R1_00001

MMDT2222A_R2_00001

For example :

RB500V-40_R2_00001

Part No.



Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



MMDT2222A

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